## FEATURES

- Ultra-lowpowerconsumption, quiet, pumplessdesign
- Two digitally controlled, 256-position potentiometers
- Serialport provides means for setting and reading both potentiometers
- Resistors can be connected in series to provide increased total resistance
- 14-pin DIP, 16-pin SOIC, 20-pin TSSOP packages
- Resistive elements are temperature compensated to $\pm 0.3$ LSB relative linearity
- Standard resistance values:
- DS1267-10~10K $\Omega$
- DS1267-50~50K $\Omega$
- DS1267-100 ~ $100 \mathrm{~K} \Omega$
- Temperature:
- Commercial: $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
- Industrial: $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$


## DESCRIPTION

The DS1267 consist of two digitally controlled solidstate potentiometers. Each potentiometer is composed of 256 resistive sections. Between each resistive section and both ends of the potentiometer are tap points which are accessible to the wiper. The position of the wiper on the resistive array is set by an 8-bit value that controlswhich tap point is connected to the wiper output. Communication and control of the device is accomplished via a 3-wire serial port interface. This interface allows the device wiper position to be read or written.

Both potentiometers can be connected in series (or stacked) for an increased total resistance with the same resolution. For multiple device-single processor environments, the DS1267 can be cascaded or daisy chained. This feature provides for control of multiple devices over a single 3-wire bus.

## PIN ASSIGNMENT




## PIN DESCRIPTION

| LO, L1 | - Low End of Resistor |
| :---: | :---: |
| H0, H1 | - High End of Resistor |
| W0, W1 | - Wiper Terminal of Resistor |
| $V_{B}$ | - Substrate Bias Voltage |
| SOUT | - Stacked Configuration Output |
| $\overline{\text { RST }}$ | - Serial Port Reset Input |
| DQ | - Serial Port Data Input |
| CLK | - Serial Port Clock Input |
| $\mathrm{C}_{\text {OUT }}$ | - Cascade Port Output |
| $V_{C C}$ | - +5 Volt Supply |
| GND | - Ground |
| NC | - No Internal Connection |
| DNC | - Do Not Connect |

The DS1267 is offered in three standard resistance values which include $10 \mathrm{~K}, 50 \mathrm{~K}$, and 100 K ohm versions. Commercial and industrial temperature parts are also available. Available packages for the device include a 14-pin DIP, 16 -pin SOIC, and 20-pin TSSOP

## OPERATION

The DS1267 contains two 256-position potentiometers whose wiper positions are set by an 8 -bit value. These two 8-bit values are written to a 17-bit I/O shift register which is used to store the two wiper positions and the stack select bit when the device is powered. A block diagram of the DS1267 is presented in Figure 1

Communication and control of the DS1267 is accomplished through a 3-wire serial port interface that drives an internal control logic unit. The 3 -wire serial interface consists of the three input signals: $\overline{\operatorname{RST}}, \mathrm{CLK}$, and DQ .

The $\overline{\operatorname{RST}}$ control signal is used to enable the 3-wire serial port operation of the device. The $\overline{R S T}$ signal is an active high input and is required to begin any communication to the DS1267. The CLKsignal input is used to provide timing synchronization for data input and output. The DQ signal line is used to transmit potentiometer wiper settings and the stack select bit configuration to the 17-bit I/O shift register of the DS1267

## DS1267 BLOCK DIAGRAM Figure 1



## I/O SHIFT REGISTER Figure 2



Transmission of data always begins with the stack select bit followed by the potentiometer-1 wiper position value and lastly the potentiometer-0 wiper position value.

Whenwiper position data is to be written to the DS1267, 17 bits (or some integer multiple) of data should always be transmitted. Transactions which do not send a complete 17-bits (or multiple) will leave the register incompleteand possibly an error in the desired wiper positions.

After a communication transaction has been completed the $\overline{\mathrm{RST}}$ signal input should be takento a low state to prevent any inadvertent changes to the device shift register. Once $\overline{\text { RST }}$ has reached a low state, the contents of the I/O shift register are loaded into the respective multiplexers for setting wiper position. A new wiper position will only engage after a RST transition to the inactive state. On device power-up the DS1267 wiper positions will be set at $50 \%$ of the total resistance or binary value 1000 0000.

## STACKED CONFIGURATION

The potentiometers of the DS1267 can be connected in series as shown in Figure 3. This is referred to as the stacked configuration and allows the user to double the totalend-to-end resistance of the part. The resolution of the combined potentiometers will remain the same as a single potentiometer but with a total of 512 wiper positionsavailable. Device resolution is defined as Rtot/256 (per potentiometer); where Rtot equals the total potentiometer resistance.

The wiper output for the combined stacked potentiometer will be taken at the $\mathrm{S}_{\text {OUT }}$ pin, which is the multiplexed outputofthe wiperofpotentiometer- 0 (WO) orpotentiom-eter-1 (W1). The potentiometer wiper selected at the Sout output is governed by the setting ofthe stack select bit (bit0) ofthe 17-bit I/O shift register. If the stack select bit has value 0 , the multiplexed output, $\mathrm{S}_{\mathrm{OU}}$, will be that of the potentiometer- 0 wiper. If the stack select bit has value 1 , the multiplexed output, $\mathrm{S}_{\text {OUt }}$, will be that of the potentiometer-1 wiper.

## STACKED CONFIGURATION Figure 3



## CASCADE OPERATION

A feature of the DS1267 is the ability to control multiple devices from a single processor. Multiple DS1267s can be linked or daisy chained as shown in Figure 4. As a data bit is entered into the I/O shift registerof the DS1267 a bit will appear at the $\mathrm{C}_{\text {OUT }}$ outputafteraminimumdelay
of 50 nanoseconds. The stack select bit of the DS1267 will always be the first out the part at the beginning of a transaction. Additionally the $\mathrm{C}_{\text {OUT }}$ pin is always active regardless of the state of $\overline{\mathrm{RST}}$. This allows one to read the I/O shift register without changing its value.

CASCADING MULTIPLE DEVICES Figure 4


The C Out output of the DS1267 can be used to drive the DQ input of another DS1267. When connecting multiple devices, the total number ofbitstransmitted is always 17 times the number of DS1267s in the daisy chain.

An optional feedback resistor can be placed betweenthe $\mathrm{C}_{\text {OUT }}$ terminal of the last device and the first DS1267 DQ input thus allowing the controlling processor to read, as well as, write data, or circularly clock data through the daisy chain. The value ofthe feedback or isolation resistor should be in the range from 1 K to 10 K ohms

When reading data via the Cout pin and isolation resistor, the $D Q$ line is left floating by the reading device When RST is driven high, bit 17 is present on the Cout pin, which is fed back to the input DQ pin through the isolation resistor. When the CLK input transitions low to high, bit 17 is loaded into the first position of the I/O shift register and bit 16 becomes present on COut and DQ of the next device. After 17 bits (or 17 times the number of DS1267s in the daisy chain), the data has shifted completely around and back to its original position. When RST transitions to the low state to end data transfer, the value (the same as before the read occurred) is loaded into the wiper-0, wiper-1, and stack select bit I/O register.

ABSOLUTE AND RELATIVE LINEARITY
Absolute linearity is defined as the difference between the actual measured output voltage and the expected outputvoltage. Figure 5 presents the test circuit used to measure absolute linearity. Absolute linearity is given in terms of a minimum increment or expected output when the wiper is moved one position. In the case of the test circuit, a minimum increment (MI) or one LSB would equal $10 / 512$ volts. The equation for absolute linearity is given as follows:

## (1) ABSOLUTE LINEARITY <br> $$
A L=\left\{\mathrm{V}_{\mathrm{O}}(\text { actual })-\mathrm{V}_{\mathrm{O}}(\text { expected })\right\} / \mathrm{MI}
$$

Relative Linearity is a measure of error between two adjacentwiper position points and is given in terms of MI by equation (2).

## (2) RELATIVE LINEARITY <br> $$
R L=\left\{V_{O}(n+1)-V_{O}(n)\right\} / M I
$$

Figure 6 is a plot of absolute linearity and relative linearity versuswiper position forthe DS1267 at $25^{\circ} \mathrm{C}$. The specification for absolute linearity of the DS1267 is $\pm 0.75 \mathrm{MI}$ typical. The specification for relative linearity of the DS1267 is $\pm 0.3 \mathrm{MI}$ typical.

## LINEARITY MEASUREMENT CONFIGURATION Figure 5



NOTE:
In this setup, $\mathrm{a} \pm 2 \%$ delta in total resistance RO to R 1 would cause a $\pm 2.5 \mathrm{MI}$ error.

DS1267 ABSOLUTE AND RELATIVE LINEARITY Figure 6


TYPICAL APPLICATION CONFIGURATIONS
Figures 7 and 8 show two typical application configurationsfor the DS1267. By connecting the wiperterminal of the partto a high impedance load, the effects of the wiper resistance is minimized, since the wiper resistance can vary from 400 to 1000 ohms depending on wiper voltage Figure 7 presents the device connected in an inverting variblegainamplifier. The gain of the circuit on Figure 7 is given by the following equation:

$$
A v=-n /(255-n) ; \text { where } n=0 \text { to } 255
$$

Figure 8 shows the deivce operaing in a fixed gain attenuator where the potentiometer is used to attenuate an incomingsignal. Note the resistance R1 is chosen to be much greater than the wiper resistance to minimize its effect on circuit gain

INVERTING VARIABLE GAIN AMPLIFIER Figure 7


FIXED GAIN ATTENUATOR Figure 8


ABSOLUTE MAXIMUM RATINGS*
Voltage on Any Pin Relative to Ground (VB=GND)
Voltage on Resistor Pins when VB $=-5.5 \mathrm{~V}$
Voltage on $V_{B}$
Operating Temperature
Storage Temperature
Soldering Temperature
-1.0 V to +7.0 V
-5.5 V to +7.0 V
-5.5 to GND
$0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ commercial; $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ industrial
$-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
$260^{\circ} \mathrm{C}$ for 10 seconds

* This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.
RECOMMENDED DC OPERATING CONDITIONS

| PARAMETER | SYMBOL | MIN | ${ }^{\circ} \mathrm{C}$ to $\left.70^{\circ} \mathrm{C} ; \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \pm 10 \%\right)$ |  |  |  |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage | $\mathrm{V}_{\mathrm{CC}}$ | 4.5 |  | MAX | UNITS | NOTES |
| Input Logic 1 | $\mathrm{~V}_{\mathrm{IH}}$ | 2.0 |  | 5.5 | V | 1 |
| Input Logic 0 | $\mathrm{~V}_{\mathrm{IL}}$ | -0.5 |  | $\mathrm{~V}_{\mathrm{CC}}+0.5$ | V | 1,2 |
| Substrate Bias | $\mathrm{V}_{\mathrm{B}}$ | -5.5 |  | +0.8 | V | 1,2 |
| Resistor Inputs | $\mathrm{L}, \mathrm{H}, \mathrm{W}$ | $\mathrm{V}_{\mathrm{B}}-0.5$ |  | GND | V | 1 |

DC ELECTRICAL CHARACTERISTICS
$\left(0^{\circ} \mathrm{C}\right.$ to $\left.70^{\circ} \mathrm{C} ; \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \pm 10 \%\right)$

| PARAMETER | SYMBOL | MIN | TYP | MAX | UNITS | NOTES |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Current | $\mathrm{I}_{\mathrm{CC}}$ |  | 22 | 650 | $\mu \mathrm{~A}$ | 12 |
| Input Leakage | $\mathrm{I}_{\mathrm{LI}}$ | -1 |  | +1 | $\mu \mathrm{~A}$ |  |
| Wiper Resistance | $\mathrm{R}_{\mathrm{W}}$ |  | 400 | 1000 | $\Omega$ |  |
| Wiper Current | $\mathrm{I}_{\mathrm{W}}$ |  |  | 1 | mA |  |
| Output Leakage | $\mathrm{I}_{\mathrm{LO}}$ | -1 |  | +1 | $\mu \mathrm{~A}$ |  |
| Logic 1 Output @ 2.4 Volts | $\mathrm{I}_{\mathrm{OH}}$ | -1 |  |  | mA | 8,9 |
| Logic 0 Output @ 0.4 Volts | $\mathrm{I}_{\mathrm{OL}}$ |  |  | 4 | mA | 8,9 |
| Standby Current | ISTBY |  | 22 |  | $\mu \mathrm{~A}$ |  |

## ANALOG RESISTOR CHARACTERISTICS

 $\left(0^{\circ} \mathrm{C}\right.$ to $\left.70^{\circ} \mathrm{C} ; \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \pm 10 \%\right)$| PARAMETER | SYMBOL | MIN | TYP | MAX | UNITS | NOTES |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| End-to-End Resistor Tolerance |  | -20 |  | +20 | $\%$ |  |
| Absolute Linearity |  |  | $\pm 0.75$ |  | LSB | 4 |
| Relative Linearity |  |  | $\pm 0.3$ |  | LSB | 5 |
| -3 dB Cutoff Frequency | FCUTOFF |  |  |  | Hz | 7 |
| Noise Figure |  |  |  |  |  | 11 |
| Temperature Coefficient |  |  | $\pm 800$ |  | $\mathrm{ppm} / \mathrm{C}$ |  |

CAPACITANCE

| PARAMETER | SYMBOL | MIN | TYP | MAX | UNITS | NOTES |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| InputCapacitance | $\mathrm{C}_{\text {IN }}$ |  |  | 5 | pF | 3 |
| OutputCapacitance | $\mathrm{C}_{\text {OUT }}$ |  |  | 7 | pF | 3 |

AC ELECTRICAL CHARACTERISTICS

| PARAMETER | SYMBOL | MIN | TYP | MAX | UNITS | NOTES |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| CLKFrequency | $\mathrm{f}_{\text {CLK }}$ | DC |  | 10 | MHz | 10 |
| Width of CLK Pulse | $\mathrm{t}_{\mathrm{CH}}$ | 50 |  |  | ns | 10 |
| Data Setup Time | $\mathrm{t}_{\mathrm{DC}}$ | 30 |  |  | ns | 10 |
| Data Hold Time | $\mathrm{t}_{\mathrm{CDH}}$ | 10 |  |  | ns | 10 |
| Propagation Delay Time Low to <br> High Level Clock to Output | $\mathrm{t}_{\text {PLH }}$ |  |  | 50 | ns | 10 |
| Propagation Delay Time High to <br> Low Level | $\mathrm{t}_{\text {PLH }}$ |  |  | 50 | ns | 10 |
| $\overline{\text { RST High to Clock Input High }}$ | $\mathrm{t}_{\mathrm{CC}}$ | 50 |  |  | ns | 10 |
| $\overline{\text { RST Low from Clock Input High }}$ | $\mathrm{t}_{\text {HLT }}$ | 50 |  |  | ns | 10 |
| $\overline{\text { RST Inactive }}$ | $\mathrm{t}_{\text {RLT }}$ | 125 |  |  | ns |  |
| Clock Low to Data Valid on a Read | $\mathrm{t}_{\mathrm{CDD}}$ |  |  | 30 | ns | 10 |
| CLK Rise Time, CLK Fall Time | $\mathrm{t}_{\mathrm{CR}}$ |  |  | 50 | ns | 10 |

## NOTES

1. All voltages are referenced to ground.
2. Resistor inputs cannot exceed the substrate bias voltage, Vb , in the negative direction.
3. Capacitance values apply at $25^{\circ} \mathrm{C}$.
4. Absolute linearity is used to determine wiper voltage versus expected voltage as determined by wiper position. Device test limits $\pm 1.6 \mathrm{LSB}$
5. Relative linearity is used to determined the change in voltage between successive tap positions. Device test limits $\pm 0.5$ LSB.
6. Typical values are for ta $=25^{\circ} \mathrm{C}$ and nominal supply voltage
7. -3 dB cutoff frequency characteristics for the DS1267 depend on potentiometer total resistance: DS1267-010; 1 MHz, DS1267-050; 200 KHz , DS1267-100; 100 KHz .
8. Cout is active regardless of the state of RST.
9. $\mathrm{V}_{\text {REF }}=1.5$ volts
10. See Figure 9(a), (b), and (c).
11. Noise $<-120 \mathrm{~dB} / \sqrt{\mathrm{Hz}}$. Reference 1 volt (thermal).
12. See Figure 11.

TIMING DIAGRAMS Figure 9

(B) START OF COMMUNICATION TRANSACTION

(C)


DIGITAL OUTPUT LOAD SCHEMATIC Figure 10


TYPICAL SUPPLY CURRENT VS. SERIAL CLOCK RATE Figure 11


DS1267E 20-PIN TSSOP


1


| DIM | MIN | MAX |
| :---: | :--- | :--- |
| A MM | - | 1.10 |
| A1 MM | 0.05 | - |
| A2 MM | 0.75 | 1.05 |
| C MM | 0.09 | 0.18 |
| L MM | 0.50 | 0.70 |
| e1 MM | 0.65 BSC |  |
| B MM | 0.18 | 0.30 |
| D MM | 6.40 | 6.90 |
| E MM | 4.40 NOM |  |
| G MM | 0.25 REF |  |
| H MM | 6.25 | 6.55 |
| phi | $0^{\circ}$ | $8^{\circ}$ |

